High Performance Schottky Rectifier, 2 x 10 A **FEATURES**

- 150 °C T_J operation
- Center tap D²PAK (TO-263AB) and TO-262AA RoHS packages COMPLIANT HALOGEN
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

-65 to +150

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform (per device)	20	٨		
I _{FRM}	$T_{\rm C} = 135 \ ^{\circ}{\rm C}$ (per leg)	20	A		
V _{RRM}		35/45	V		
I _{FSM}	t _p = 5 μs sine	1060	A		
V _F	10 A _{pk} , T _J = 125 °C	0.57	V		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRB2035CT-M3 VS-MBR2035CT-1-M3	VS-MBRB2045CT-M3 VS-MBR2045CT-1-M3	UNITS
Maximum DC reverse voltage	V _R	35	45	V
Maximum working peak reverse voltage	V _{RWM}		40	V

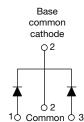
VS-MBR20..CT-1-M3

Range

PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _R	35 V, 45 V			
V _F at I _F	0.72 V			
I _{RM} max.	15 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	8 mJ			
Package	D ² PAK (TO-263AB), TO-262AA			
Circuit configuration	Common cathode			

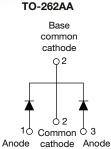
D²PAK (TO-263AB)

SHAY



Anode cathode Anode

VS-MBRB20..CT-M3



VS-MBRB20..CT-M3, VS-MBR20..CT-1-M3

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TJ

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FREE



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ABSOLUTE MAXIMUM RATI	NGS				
PARAMETER	SYMBOL	1	TEST CONDITIONS	VALUES	UNITS
Maximum average per leg		T _C = 135 °C, rate	d V-	10	
forward current per device	I _{F(AV)}	1C = 155 C, fate	u v _R	20	
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square	wave, 20 kHz, T _C = 135 °C	20	
Non repetitive peak ourge ourgent		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	A
Non-repetitive peak surge current	IFSM	Surge applied at single phase, 60 l	rated load conditions halfwave, Hz	150	
Non-repetitive avalanche energy per leg	E _{AS}	$T_{J} = 25 \text{ °C}, I_{AS} = 25 \text{ °C}$	2 A, L = 4 mH	8	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying Frequency limited V _A = 1.5 x V _R typi	, ,	2	А

ELECTRICAL SPECIFICAT	IONS				
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		VALUES	UNITS
		20 A	T _J = 25 °C	0.84	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _ 125 °C	0.57	V
		20 A	– T _J = 125 °C	0.72	
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	m۸
reverse current	IRM (1)	T _J = 125 °C	haled DC vollage	15	mA
Threshold voltage	V _{F(TO)}			0.354	V
Forward slope resistance	r _t	$T_J = T_J$ maximum		17.6	mΩ
Maximum junction capacitance	CT	V _R = 5 V _{DC} (test signal rang	ge 100 kHz to 1 MHz), 25 °C	600	pF
Typical series inductance	L _S	Measured from top of term	inal to mounting plane	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-65 to 150	ъ	
Maximum storage temperature range	T _{Stg}		-65 to 175	U	
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	2.0	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	C/W	
Approvimeto weight			2	g	
Approximate weight			0.07	oz.	
Mounting torgueminimum		Non-lubricated threads	6 (5)	kgf ⋅ cm	
maximum		Non-Inducated threads	12 (10)	(lbf ⋅ in)	
		Case style D ² PAK (TO-263AB)	MBRB2	2035CT	
Marking davias		Case style D-PAK (TO-263AB)	MBRE		
Marking device		Copp style TO 26244	MBR20	35CT-1	
		Case style TO-262AA	MBR20	45CT-1	

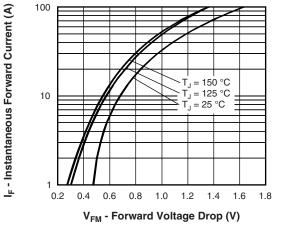
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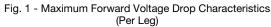
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VS-MBRB20..CT-M3, VS-MBR20..CT-1-M3

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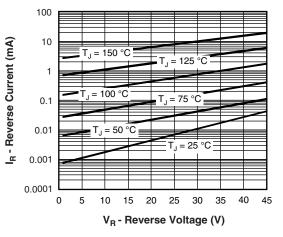


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

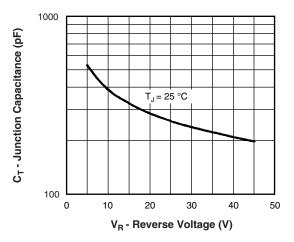
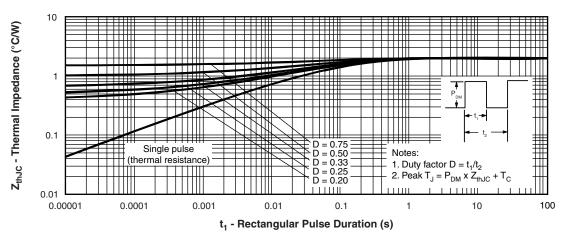


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



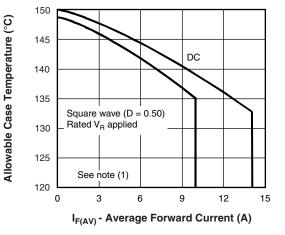


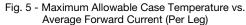
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VS-MBRB20..CT-M3, VS-MBR20..CT-1-M3

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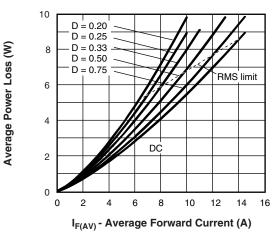


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

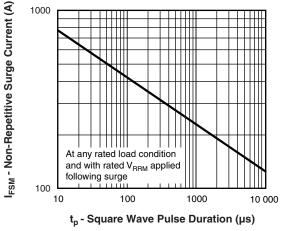


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

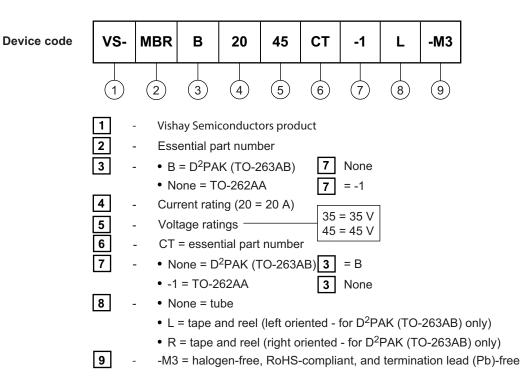
Note

 $^{(1)} \mbox{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{ forward power loss = } I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \mbox{ inverse power loss = } V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ rated \ V_R$



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-MBRB2035CT-M3	50	Antistatic plastic tubes			
VS-MBRB2045CTL-M3	800	13" diameter plastic tape and reel			
VS-MBRB2045CT-M3	50	Antistatic plastic tubes			
VS-MBRB2045CTR-M3	800	13" diameter plastic tape and reel			
VS-MBR2035CT-1-M3	50	Antistatic plastic tubes			
VS-MBR2045CT-1-M3	50	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions D ² PAK (TO-263AB)		www.vishay.com/doc?96164			
Dimensions —	TO-262AA	www.vishay.com/doc?96165			
Part marking information —	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information —	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			
SPICE model		www.vishay.com/doc?95504			

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		0.100 BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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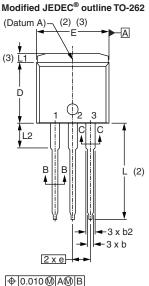
Outline Dimensions

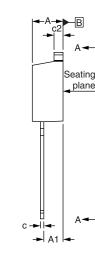


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TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

CVMPOI	MILLIN	MILLIMETERS		HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis and the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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